

SPDT RF Switch

VSW2-33-10W+

 50Ω 50 to 3000 MHz Reflective RF Switch 10 W Positive Control Voltage; +3 V to +5 V

THE BIG DEAL

- High Power, 10 W (Cold Switching)
- Good Isolation, 26 dB Typ. at 1 GHz
- Low Insertion Loss, 0.5 dB Typ. at 1 GHz
- High IP3, +56 dBm Typ. at 1 GHz
- Small Size, 3x2x0.89 mm
- Aqueous Washable



+RoHS Compliant
The +Suffix identifies RoHS Compliance.
See our website for methodologies and qualifications

APPLICATIONS

- Automated Switching Networks
- Cellular/ PCS
- ISM, WCDMA, WiMAX, LTE, TD-SCDMA

PRODUCT OVERVIEW

The VSW2-33-10W+ is a PHEMT high power reflective SPDT switch operates with positive control voltage while consuming, $20 \mu A$ typical. Compared to competitive models, it operates over a wide frequency range, 50 to 3000 MHz and control voltages up to +5 V. It is packaged in a tiny 2x3x1 mm package and is rated MSL1 and class 1A for HBM.

KEY FEATURES

Features	Advantages
Broadband, 50 to 3000 MHz	Covers a range of wireless applications such as Cellular, PCS, LTE, WiMAX, Avionics, Broadcast, CATV, GPS, Radar, etc.
High Input Power, 10 W (Cold Switching) at +5 V Control	Suitable for Transmit/receive switching.
Low Insertion Loss, 0.5 dB Typ. at 1 GHz	Premium high power is transmitted with minimal loss and temperature rise of the DUT. In receive path results in minimal increase of system noise figure.
Positive Control Voltage, 0/+3 V or 0/+5 V	No external components are required for change of operating voltage from +3 to +5 V.
Good Isolation, 26 dB to 1 GHz and 18 dB to 3 GHz	Minimizes filtering requirement.

REV. B ECO-026600 VSW2-33-10W+ MCL NY 250818





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RF ELECTRICAL SPECIFICATIONS¹, $T_{AMB} = +25$ °C, $V_{CTL} = +3$ V TO +5 V

Paramet	er	Condition (MHz)	Min.	Тур.	Max.	Units
Frequency Range			50		3000	MHz
		50		0.4		
		500		0.4	0.6	
Insertion Loss ²		1000		0.5	0.7	dB
		2000		0.6	0.8	
		3000		0.6	0.8	
		50		42		
		500	28	31		
Isolation (From RF COM to RF1/RF2 and	RF1 to RF2 Ports)	1000	23	26		dB
(From the first 2 and	111 2 10 111 2 1 0 1 10)	2000	17	22		
		3000	15	18		
		50		24		
. .		500		27		
Return Loss (ON STATE)		1000		21		dB
(3.1.2.7.1.2,		2000		17		
		3000		19		
		100		+55		
		500		+56		
Input IP3		1000		+56		dBm
		2000		+55		
				+53		
$V_{CTL} = +3 \text{ V}$ Operating Power ^{3,4,5} (Cold Switching) $V_{CTL} = +5 \text{ V}$		50			7	
	// -+3//	1000			7	
	V _{CTL} - 13 V	2000			7	
		3000			7	W
	V - +5 V	50			10	VV
		1000			10	
	2000			9		
	3000			7		

^{1.} Tested on Mini-Circuits' test board TB-530+, (see Characterization Test Circuit, Fig. 1).

DC ELECTRICAL SPECIFICATIONS

Paramete	er	Min.	Тур.	Max.	Units	
Control Voltage Low (V _{CTL})		0		0.2	V	
Control Voltage High (V _{CTL})		2.8		5.2	V	
Cantual Commant at	(V _{CTL}) = +3 V		20			
Control Current at	$(V_{CTL}) = +5 V$		42		μΑ	

^{2.} Insertion loss values are de-embedded from test board loss.

^{3.} Do not exceed RF input power as shown in Absolute Maximum Rating table.

^{4.} Derate linearly to 3 W at +85°C ground lead temperature.

^{5.} Compression 0.1 dB typ. over 1000-3000 MHz and 0.5 dB typical at 50 MHz at max. operating power.



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SWITCHING SPECIFICATIONS

Parameter	Control Voltage (V)	Min.	Тур.	Max.	Units	
Rise/Fall Time (10 to 90% or 90 to 10% RF)	0/+3		433			
RISE/ Pail Time (10 to 90% of 90 to 10% RF)	0/+5		150		ns	
Switching Time FOW CTDI to 00/10% DE	0/+3		550		ns	
Switching Time, 50% CTRL to 90/10% RF	0/+5		306			
Video Food Through (Control Otto 12) / From - F00 (/ lp)	0/+3		20			
Video Feed-Through, (Control 0 to +3 V, Freq. = 500 KHz)	0/+5		28		$mV_{P,P}$	

ABSOLUTE MAXIMUM RATINGS⁶

Parameter	Ratings
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C
Control Voltage	+10 V
DE La La Daniera	22 W, 50-2000 MHz
RF Input Power	17 W, 2000-3000 MHz

^{6.} Operation of this device above any of these conditions may cause permanent damage.

TRUTH TABLE

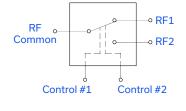
(State of control voltage selects the desired switch state)

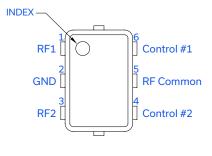
State of Control Voltage		RF Common to	
V _{CTL1}	V_{CTL2}	RF1	RF2
LOW	HIGH	OFF	ON
HIGH	LOW	ON	OFF
LOW	LOW	N/A	N/A
HIGH	HIGH	N/A	N/A

ON - Low Instertion Loss State

OFF - Isolation State

SIMPLIFIED SCHEMATIC AND PAD DESCRIPTION





Function	Pad Number	Description
RF COM	5	RF Common/SUM Port, Requires DC block (see Fig. 2)
RF1	1	RF Out #1/In Port #1, Requires DC block (see Fig. 2)
RF2	3	RF Out #2/In Port #2, Requires DC block (see Fig. 2)
Control #1 (V _{CTL1})	6	Control IN #1
Control #2 (V _{CTL2})	4	Control IN #2
GND	2	RF DC Ground



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CHARACTERIZATION TEST CIRCUIT

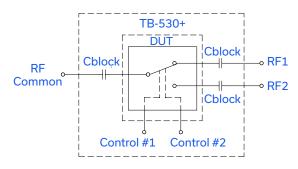


Figure 1. Block Diagram of Test Circuit Used for Characterization (DUT Soldered on Mini-Circuits' TB-530+, Cblock = 1000 pF)

Test Equipment:

For Insertion Loss, Isolation, Return Loss and DC Current:

Agilent's N5230A Network Analyzer, E3631A power supply.

For Switching Time and DC Current:

Agilent's 54832B oscilloscope, 81110A pulse generator and E3631A power supply. For Input IP3:

Agilent's E8257D signal generators, E4418B power meter, N9020A Signal analyzer and E3631A power supply.

For Compression:

LZY-1+/LZY-2+/ZHL-900A-10W/ZHL-16W-43+ amplifier as driver amplifier at RF Common.

Agilent's N5230A Network Analyzer, E3631A power supply

Conditions:

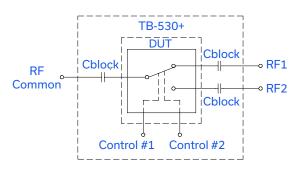
Control = 0 and +3 V/+5 V

For Insertion Loss, Isolation and Return Loss: $P_{IN} = 0$ dBm

For Input IP3: P_{IN} = +5 dBm/tone

For Switching Time: RF frequency: 500 MHz at 0 dBm, Control Frequency: 100 KHz and 0 and +3 V/+5 V $\,$

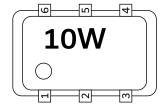
RECOMMENDED APPLICATION CIRCUIT



Frequency	Cblock
(MHz)	(Suggested Value)
50-3000	1000 pF

Figure 2. Evaluation board includes case, connectors, and components soldered to PCB.

PRODUCT MARKING



Marking may contain other features or characters for internal lot control.



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ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASHBOARD. TO ACCESS

CLICK HERE

	Data Table	
Performance Data		
	Swept Graphs	
Case Style	JZ1436 Plastic package, Lead Finish: Matte Tin	
Tape & Reel	F93	
	7// Paraller 11/20, 50, 400, 200, 500, and 1000, do 1/200	
Standard Quantities Available on Reel	7" Reels with 20, 50, 100, 200, 500, or 1000 devices 13" Reels with 3000 devices	
	25 110505 111111 25505 1101110	
Suggested Layout for PCB Design	PL-324	
Evaluation Board	TB-530+	
Environmental Ratings	ENV41	

ESD RATING

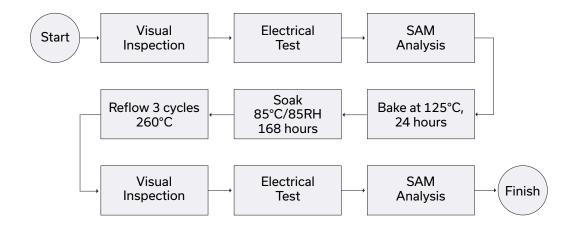
Human Body Model (HBM): Class 1A (250 to < 500 V) in accordance with JESD22-A114

Machine Model (MM): Class A (Passes 150 V) in accordance with JESD22-A115

MSL RATING

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

MSL TEST FLOW CHART



NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/terms/viewterm.html